Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.30$ V at $I_F = 5.0$ A



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VBT3045CBP

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V _{RRM}	45 V			
I _{FSM}	200 A			
V _F at I _F = 15 A	0.39 V			
T _{OP} max. (AC mode)	150 °C			
T _J max. (DC forward current)	200 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation



HALOGEN

FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT3045CBP	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	- I _{F(AV)} ⁽¹⁾	30	٨	
	per diode		15	A	
Peak forward surge current 8.3 ms single half sine-w superimposed on rated load per diode	I _{FSM}	200	А		
Operating junction and storage temperature range (AC mode)		T _{OP} , T _{STG}	-40 to +150	°C	
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$		T _J ⁽²⁾	≤ 200	°C	

Notes

⁽¹⁾ With heatsink

(2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C		0.42	-	V
	I _F = 7.5 A			0.44	-	
	I _F = 15 A			0.49	0.57	
	I _F = 5 A	T _A = 125 °C		0.30	-	
	I _F = 7.5 A			0.33	-	
	I _F = 15 A			0.39	0.48	
Reverse current per diode	V _B = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	2000	μA
	$v_{\rm R} = 45 v$ $T_{\rm A} = 1$	T _A = 125 °C		17	50	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL VBT3045CBP		UNIT	
Turping thermal registerion	per diode	R _{eJC}	1.6	°C/W	
Typical thermal resistance	per device		0.85		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
D ² PAK (TO-263AB)	VBT3045CBP-M3/4W	1.38	4W	50/tube	Tube	
D ² PAK (TO-263AB)	VBT3045CBP-M3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

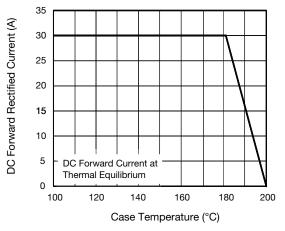


Fig. 1 - Maximum Forward Current Derating Curve

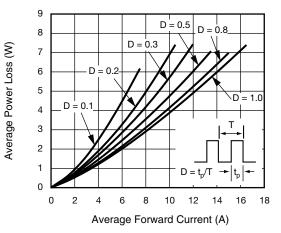
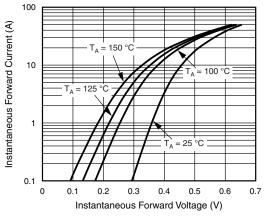


Fig. 2 - Forward Power Loss Characteristics Per Diode



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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

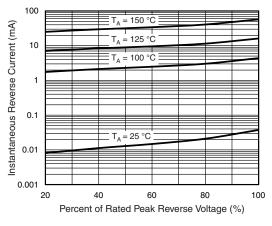
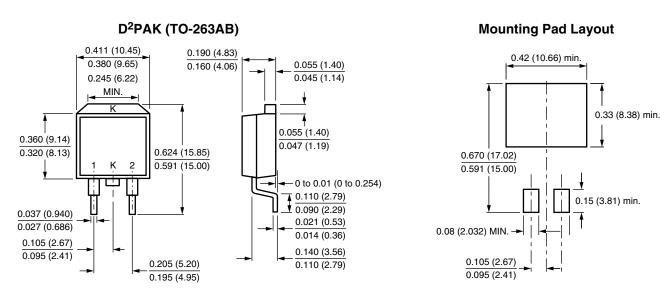


Fig. 4 - Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



(100 000) (100

Fig. 5 - Typical Junction Capacitance Per Diode

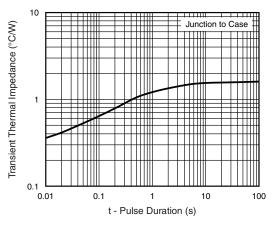


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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